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# $\alpha$ and $\gamma$ mixed-phase $\text{Ga}_2\text{O}_3$ as a photocatalyst for $\text{CO}_2$ reduction with water: mechanism and the role of each phase

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Gallium oxides ( $\text{Ga}_2\text{O}_3$ ) with mixed phases of  $\alpha/\beta$ ,  $\beta/\gamma$ , and  $\alpha/\gamma$  are known to show high catalytic activity for the photoreduction of  $\text{CO}_2$  with water to produce  $\text{CO}$ ,  $\text{H}_2$  and  $\text{O}_2$ . However, the roles of each phase and phase mixing in the photocatalytic  $\text{CO}_2$  reduction have not been well understood. In this study, we have synthesized  $\alpha/\gamma$  mixed-phase  $\text{Ga}_2\text{O}_3$  with controlled mixing ratios and examined their catalytic activity in the photoreduction of  $\text{CO}_2$  with water. The catalytic activity or the production rates of  $\text{H}_2$  and  $\text{CO}$  appreciably changed with the  $\gamma/\alpha$  mixing ratio. The  $\text{H}_2$  formation dominated on the  $\alpha$ -phase, while the  $\text{CO}$  production increased with increasing the  $\gamma$ -phase content and attained the maximum for a  $\gamma$ -content of 40%. Above 60%, both the  $\text{H}_2$  and  $\text{CO}$  production rates significantly decreased to the similar rates of the pure  $\gamma$ -phase. TEM observations of the mixed-phase  $\text{Ga}_2\text{O}_3$  revealed the coexistence of spheroid type  $\alpha$ - $\text{Ga}_2\text{O}_3$  particles with smaller polyhedral type  $\gamma$ - $\text{Ga}_2\text{O}_3$  which was not well crystallized to show a large surface area. In the  $\alpha/\gamma$  mixed-phase  $\text{Ga}_2\text{O}_3$ ,  $\gamma$ - $\text{Ga}_2\text{O}_3$  was embedded in  $\alpha$ - $\text{Ga}_2\text{O}_3$  with  $\gamma$ -phase contents less than 40%, while  $\gamma$ - $\text{Ga}_2\text{O}_3$  covered  $\alpha$ - $\text{Ga}_2\text{O}_3$  above 60%. Considering that the  $\text{H}_2$  and  $\text{CO}$  production rates change with the  $\gamma/\alpha$  mixing ratio, we have revealed a reaction mechanism of  $\text{CO}$  production that some of the H produced on the  $\alpha$  phase by water splitting is used to reduce  $\text{CO}_2$  adsorbed on the  $\gamma$ -phase which has a much larger specific surface area than that of the  $\alpha$ -phase but less catalytic activity than the  $\alpha$ -phase.

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## Introduction

Gallium oxides ( $\text{Ga}_2\text{O}_3$ ) have been attracting large interest as photocatalysts for water splitting,  $\text{CO}_2$  reduction with water,  $\text{CO}_2$  conversion into green fuels/chemicals, and degradation of pollutant chemicals.<sup>1</sup> In most studies of the  $\text{CO}_2$  reduction with water using  $\text{Ga}_2\text{O}_3$  as a photocatalyst, Ag or some metal oxides have been used as cocatalysts or dopants.<sup>2–6</sup> Recently it has been reported that  $\text{Ga}_2\text{O}_3$  works well as the photocatalyst for the  $\text{CO}_2$  reduction without cocatalysts.<sup>7–12</sup>  $\text{Ga}_2\text{O}_3$  exhibits six different crystalline phases of  $\alpha$ ,  $\beta$ ,  $\gamma$ ,  $\delta$ ,  $\epsilon$ , and  $\kappa$ , and a significant increase of the catalytic activity is reported with using mixed-phase  $\text{Ga}_2\text{O}_3$ , for example,  $\alpha/\beta$  mixed phases,  $\gamma/\beta$  mixed phases,  $\gamma/\beta$  phases +  $\text{GaOOH}$ , and  $\text{GaOOH}/\alpha$ -phase.<sup>9–12</sup> Aoki *et al.* have indicated that on  $\alpha$ - $\text{Ga}_2\text{O}_3$ , photocatalytic water splitting dominates and the resulting hydrogen is used for  $\text{CO}_2$

reduction.<sup>9,12</sup> However, the effects of phase mixing or mechanism of enhancing the catalytic activity are not well known.

In this work, we have synthesized  $\text{Ga}_2\text{O}_3$  consisting of the mixed phase of  $\alpha$  and  $\gamma$  with different mixing ratios in order to investigate the roles of each phase in the photocatalytic  $\text{CO}_2$  reduction and the mechanism of the enhancement of its catalytic activity. For the synthesis of  $\alpha/\gamma$  mixed-phase  $\text{Ga}_2\text{O}_3$ , a previously reported method by Li *et al.* was employed in which  $\text{GaOOH}$  and  $\text{Ga}(\text{OH})_3$  were used as precursors of  $\alpha$ - $\text{Ga}_2\text{O}_3$  and  $\gamma$ - $\text{Ga}_2\text{O}_3$ , respectively.<sup>13</sup> Controlling preparation conditions carefully, we have succeeded in synthesizing the mixed-phase  $\text{Ga}_2\text{O}_3$  with controlled mixing ratios for the first time and the mixing ratios of  $\alpha/\gamma$  phases in the synthesized mixed-phase  $\text{Ga}_2\text{O}_3$  were determined by XAFS analyses.

The synthesized mixed-phase  $\text{Ga}_2\text{O}_3$  was subjected to photocatalytic  $\text{CO}_2$  reduction with water as the photocatalyst. The production rates of  $\text{H}_2$  and  $\text{CO}$ , major products of the  $\text{CO}_2$  reduction, were analyzed in terms of the  $\alpha/\gamma$  mixing ratio, specific surface area, grain (crystalline) size, particle size and morphology. The analysis leads us to conclude that the  $\alpha$ -phase is quite effective for water splitting and the H produced by the water splitting reduces  $\text{CO}_2$  dominantly adsorbed on the  $\gamma$ -phase. Accordingly, the maximum  $\text{CO}$  production rate appeared for the sample containing 40%  $\gamma$ -phase with a morphology of

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small  $\gamma$ -phase grains embedded in a little larger  $\alpha$ -phase particle.

## Experimental

### Preparation of photocatalyst samples

Photocatalyst samples of  $\alpha/\gamma$  mixed-phase  $\text{Ga}_2\text{O}_3$  were prepared by the following way. At first, the mixture of  $\text{GaOOH}$  and  $\text{Ga}(\text{OH})_3$  was prepared by the impregnation method and the mixture was calcined to convert  $\text{GaOOH}$  and  $\text{Ga}(\text{OH})_3$  to  $\alpha$ - $\text{Ga}_2\text{O}_3$  and  $\gamma$ - $\text{Ga}_2\text{O}_3$ , respectively as reported by Li *et al.*, T. Sato *et al.* and Y. Hou *et al.*<sup>13–15</sup> A fixed amount of  $\text{Ga}(\text{NO}_3)_3 \cdot 8\text{H}_2\text{O}$  (KISHIDA Chemical Corporation, purity 99%) was dissolved into distilled water or ethanol and stirred for 1 hour. Then 28 mol%  $\text{NH}_3$  aq. (FUJIFILM Wako Pure Chemical Corporation) solution was added in drops keeping constant pH. The deposits consisted of  $\text{GaOOH}$  and  $\text{Ga}(\text{OH})_3$  and their mixing ratio was controlled by changing the stirring time and pH. Then the deposits were rinsed with distilled water, dried at 60 °C for a specified time, and calcined at 673 K in air for 4 hours resulting in the  $\alpha/\gamma$  mixed-phase  $\text{Ga}_2\text{O}_3$ . Detailed conditions for sample preparation are given in Table 1.

### Characterization

Prepared  $\alpha/\gamma$  mixed-phase  $\text{Ga}_2\text{O}_3$  samples were characterized by X-ray diffraction analysis (XRD), scanning electron microscopy (SEM), transmission electron microscopy (TEM), specific surface area measurements, UV-vis diffuse reflection spectroscopy, and X-ray Absorption Fine Structure (XAFS) analysis. XRD patterns were recorded using a MiniFlex 600 instrument (Rigaku) at a voltage of 40 kV and current of 15 mA with Cu  $K\alpha$  as the radiation source. The XRD patterns were collected at 20–80° in the  $2\theta$  angle scan. The  $2\theta$  scan step was 0.02° and the angle scanning rate of an X-ray detector was 10° min<sup>-1</sup>. SEM

images were observed using a field emission scanning electron microscope (FE-SEM, JSM-6500F, JEOL Ltd) with a back-scattered electron mode under an acceleration voltage of 15 kV. TEM images were observed using a transmission electron microscope (JEM-2100Plus, JEOL Ltd) under an acceleration voltage of 200 kV. Specific surface areas (SSA) of all samples were measured by the BET method with a Monosorb<sup>TM</sup> instrument (Quantachrome). Before the BET measurements, each sample was heated at 573 K for 3 h under a nitrogen atmosphere. UV-vis spectra were obtained using a UV-visible near-infrared absorbance photometer (V-670, JASCO) with the diffuse reflection method using  $\text{Ba}_2\text{SO}_4$  as the reference. The spectra were collected in the wavelength range of 190–850 nm. Ga K-edge XAFS measurements were performed at the Aichi Synchrotron Radiation Center BL5S1 or BL11S2 by the transmission method with using Si(111) double crystals, and the ionization chambers were filled with 90%  $\text{N}_2$  and 10% Ar for incident X-rays ( $I_0$ ) and 70%  $\text{N}_2$  and 30% Ar for transmitted X-rays ( $I$ ).

### Photocatalytic reduction of $\text{CO}_2$ with water

Photocatalytic  $\text{CO}_2$  reduction with  $\text{H}_2\text{O}$  under UV light irradiation was performed using the sample of 0.1 g dispersed in an aqueous solution of 0.5 M  $\text{NaHCO}_3$  set in a fixed-bed flow quartz reactor cell under  $\text{CO}_2$  gas flow. The UV light given by a Xe lamp through the UV cold mirror was illuminated with the light intensity of 40 mW cm<sup>-2</sup> at 254 ± 10 nm.  $\text{CO}_2$  gas was flowed into the cell with a flow rate of 3 mL min<sup>-1</sup>. The inside of the cell was stirred with a magnetic stirrer during the reaction. The reaction products ( $\text{H}_2$ ,  $\text{O}_2$  and CO) were analyzed quantitatively using a gas chromatograph equipped with a thermal conductivity detector every one hour up to five hours or longer to confirm the steady state production rates.

Table 1 Conditions for the synthesis and results of characterization for  $\alpha$ - $\text{Ga}_2\text{O}_3$ ,  $\alpha/\gamma$ - $\text{Ga}_2\text{O}_3$  and  $\gamma$ - $\text{Ga}_2\text{O}_3$

Preparation condition	Sample number																		
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
$\gamma$ phase concentration <sup>b</sup> (%)	0	0	3	4	5	7	15	19	24	40	50	56	58	61	63	79	80	92	100
Prepared Ga solution concentration (M)	0.1	0.05	0.10	0.1	0.1	0.1	0.15	0.05	0.1	0.1	0.2	0.1	0.1	0.1	0.1	0.1	0.2	0.2	0.1
Solvents	$\text{H}_2\text{O}$	EtOH																	
Volume (mL)	100	100	100	100	100	100	100	200	100	100	100	100	100	100	100	100	50	50	100
Cover	×	○	○	○	○	○	○	○	○	×	○	○	×	○	○	○	○	○	○
Temperature (°C)	50	50	50	50	50	50	50	50	50	50	50	50	50	50	0	0	0	50	0
pH	9	9	9	8	9	9	9	9	9	9	9	10	9	9	10	10	12	9	10
Stirring time (h)	3	1	5	1	3	1	1	1	1	5	1	1	1	0	0	0	0	1	0
Drying temperature (°C)	60	60	60	60	60	60	60	60	60	60	60	60	60	60	25	25	25	60	25
Drying time (h)	24	15	24	15	24	15	15	15	24	24	15	15	24	15	1	15	15	15	15
Specific surface area (m <sup>2</sup> g <sup>-1</sup> )	42.79	38.54	39.09	46.33	36.12	44.17	51.46	62.35	59.49	45.93	68.75	64.5	82.91	94.27	72.3	81.58	106.15	91.36	129.09
Crystallite size of the $\alpha$ phase <sup>a</sup>	54.5	55	57	63.5	59.5	52.4	43.9	61.4	54.3	40.7	36.7	37.4	35.4	31.6	31.7	32.7	28.8	31.5	

<sup>a</sup> Determined by XAFS analysis with the Ga K-edge. <sup>b</sup> Determined by XRD analysis using the (110) diffraction of  $\alpha$ - $\text{Ga}_2\text{O}_3$ .



## Results

### Characterization

Fig. 1(a) and (b) show the XRD patterns of some samples before and after calcination, respectively. Before the calcination, sample 1 and sample 19 exhibited the single phase of GaOOH and Ga(OH)<sub>3</sub>, respectively, and the other samples their mixtures. After the calcination, sample 1 (GaOOH) and sample 19 (Ga(OH)<sub>3</sub>) turned to be the fully  $\alpha$ -phase ( $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>) and  $\gamma$ -phase ( $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>), respectively, while the other samples turned to be the mixture of the  $\alpha$ -phase and the  $\gamma$ -phase (referred as to  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples).

The XRD peaks of the  $\alpha$ -phase were sharp enough to determine their crystallite sizes in the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples from the full width at half maximum (FWHM) of the (110) peak of the  $\alpha$ -phase. The determined crystallite sizes are given in the bottom column of Table 1 and plotted against  $\gamma$  phase contents in Fig. 2. As seen in the figure, the size decreased almost linearly with increasing the  $\gamma$  phase content. On the other hand, the XRD peaks of the  $\gamma$ -phases were very broad indicating poor crystallization. This makes it impossible to determine the crystallite sizes of the  $\gamma$ -phase from the FWHM. It also makes it hard to determine the mixing ratio of  $\alpha/\gamma$  phases ( $\alpha/\gamma$  phase

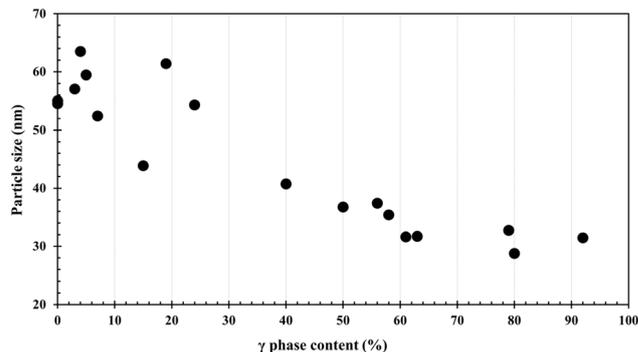


Fig. 2 Changes of crystallite size determined by XRD analysis using the (110) diffraction of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> with the contents of the  $\gamma$  phase.

ratio) in the samples with the X-ray peak intensity ratio of both the phases. Therefore, the  $\alpha/\gamma$  phase ratios represented as the  $\gamma$  contents in the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples were determined with the quantitative structural analysis using XANES and EXAFS as follows.

In Fig. 3(a) are compared three Ga K-edge XANES for  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>,  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> and sample 10 ( $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub>) with the inset of an enlarged one. Quantitative structural analysis using XANES is

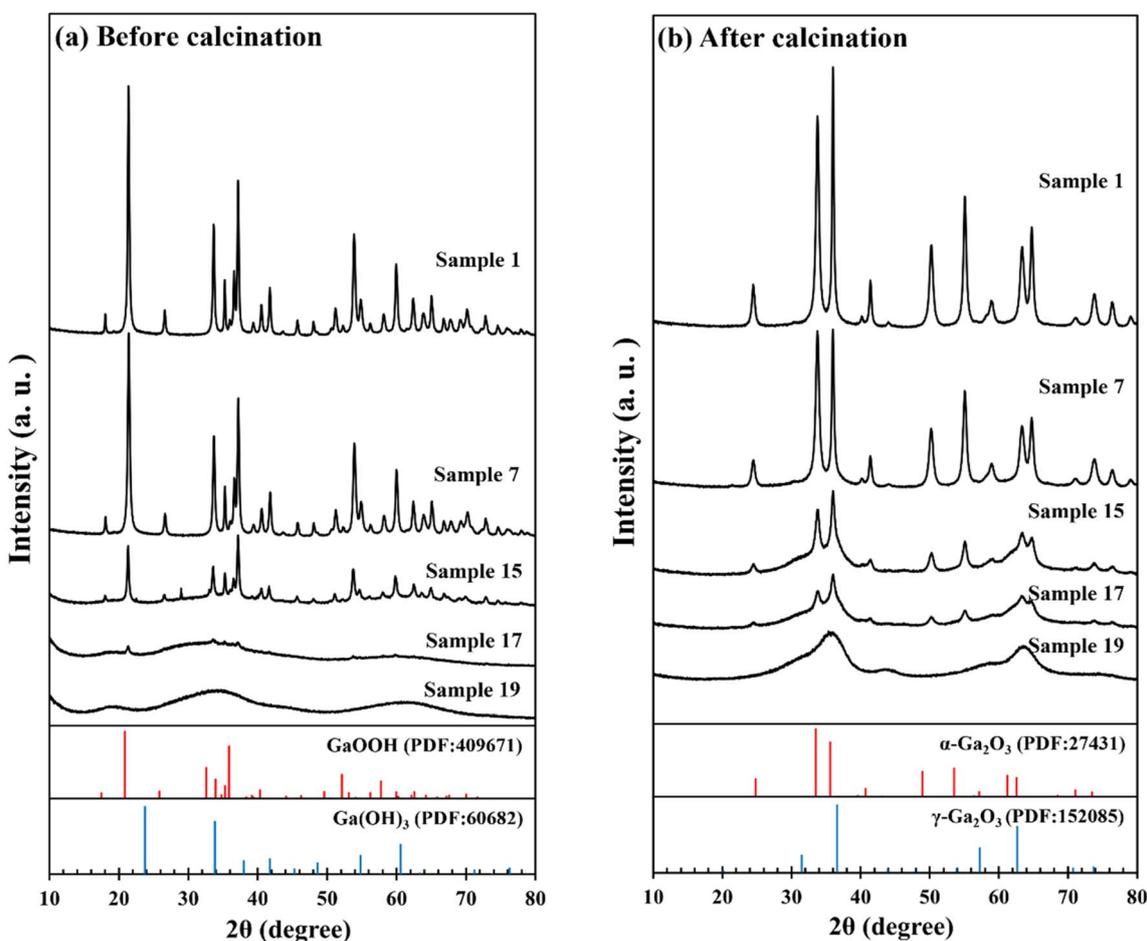


Fig. 1 XRD patterns of samples (a) before and (b) after calcination.



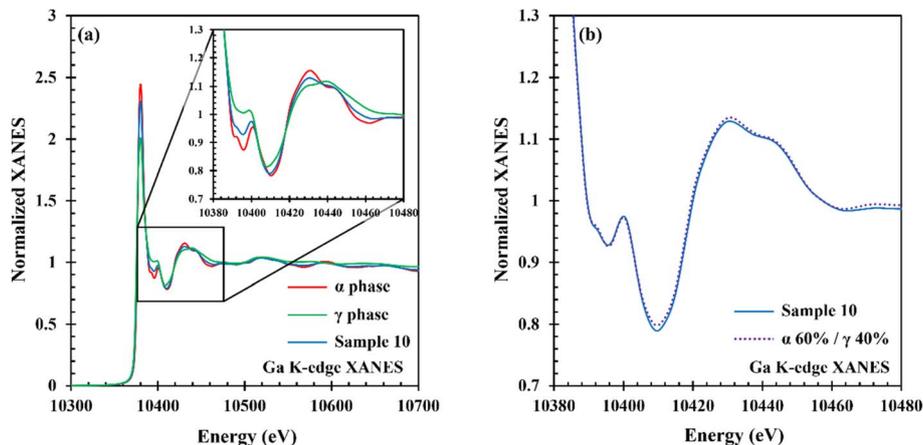


Fig. 3 (a) Ga K-edge XANES spectra of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>,  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>, and  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples with enlarged views. (b) Least square fitting to the observed spectra with a linear combination of the spectra of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> (60%) and  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> (40%).

usually performed with microstructures that appeared at higher energy than the XANES absorption edge. As seen in Fig. 3(a), the difference in crystalline phases is apparent. Assuming the fine structures of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> and  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> were kept in  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples, the fine structure of the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> sample was reproduced by the linear combination of those of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> and  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> with changing the combination ratio. The best fit result for sample 10 in Fig. 3(a) is given in Fig. 3(b) as the superposition of the observed one and reproduced one with a combination ratio of 60%  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> and 40%  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>. The reproduction by the linear combination was quite well with an error of a few %. Similar analysis was done for EXAFS as shown in Fig. 4. Fig. 4(a) is those for  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>,  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>, and sample 10 and Fig. 4(b) compares the linear combination of EXAFS of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> and  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> with EXAFS of sample 10. The EXAFS analysis gave a quite similar  $\alpha/\gamma$  mixing ratio to the XANES analysis. Thus, the determined mixing ratios of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> and  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> ( $\alpha/\gamma$  mixing ratio) in all samples are given in the top column of Table 1 as the content of the  $\gamma$ -phase (%).

The results of BET specific surface area measurements are given Table 1 in the second line from the bottom, and are

plotted against the  $\gamma$ -phase contents determined by the XANES analysis in Fig. 5. It is interesting to note that the specific surface area increases roughly linearly with the  $\gamma$ -phase content.

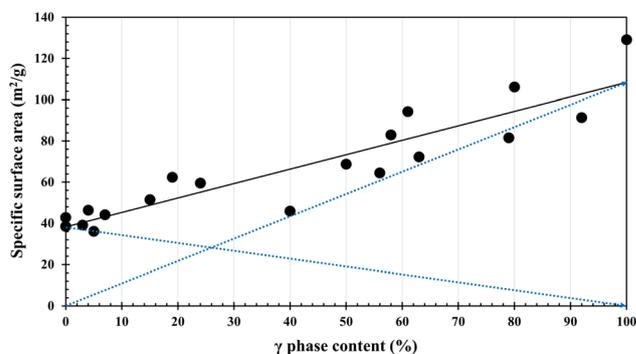


Fig. 5 Changes of BET specific surface area with  $\gamma$  phase contents. Lines are for guide to the eye. As seen in two dotted line lines, the surface areas are well represented with the linear combination of the surface areas of each phase.

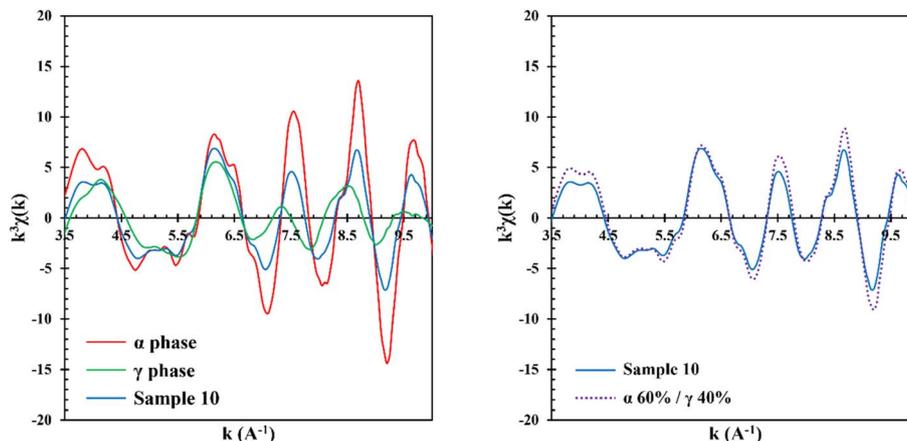


Fig. 4 (Right) Ga K-edge EXAFS spectra of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>,  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> and  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples. (Left) Least square fitting to the observed spectra with a linear combination of the spectra of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> (60%) and  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> (40%).



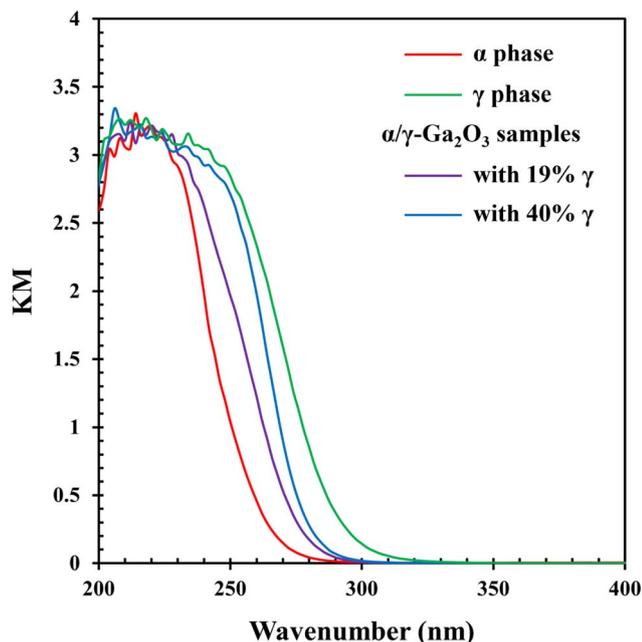


Fig. 6 UV-vis spectra of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>,  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> and  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples with  $\gamma$  phase contents of 19% and 40%.

Fig. 6 shows the UV-vis spectra of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>,  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> and  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples. Although their band gap widths decreased with increasing  $\gamma$ -phase contents, no significant change appeared. This is consistent with the smooth changes of the BET surface area in Fig. 5.

### Morphology

Fig. 7 shows the SEM images of (a)  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>, (b) sample 10 ( $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub>) and (c)  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>.  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> consists of spheroid type particles uniformly with a length of nearly 1  $\mu$ m. In the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples, with increasing the  $\gamma$ -phase contents, their particle sizes gradually increased accompanying structure disorder or surface roughening. For higher  $\gamma$ -phase containing samples, the particle shape changed to polygons with random sizes. Fig. 8 shows the TEM images of (a)  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>, (b) sample 10 ( $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub>) and (c)  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> respectively corresponding to Fig. 7. The images clearly show that every particle observed in SEM consisted of small crystallites. In  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> (Fig. 8(a)) spheroid type crystallites with a length of several tens of nm were

unidirectionally aligned, while those in  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> (Fig. 8(c)) were polygons (or rather spherical) with sizes of less than 10 nm. The size of the spheroid type crystallite in the  $\alpha$  phase is consistent with the particle sizes determined by the XRS analysis, ranging from 70 to 30 nm (see Table 1). The smaller crystallite size of the  $\gamma$ -phase well corresponds to its larger BET surface area. The  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> sample (Fig. 8(b)) seems to be consisting of two different shaped particles of spheroids and polygons. To confirm this mixing of  $\gamma$ -phase and  $\alpha$ -phase, the diffraction patterns of several localized areas in the particles of the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> sample were observed Fig. 8(d) and (e) are typical examples of the TEM image the particle and the diffraction pattern which consisted of diffraction spots assigned to (110) and (300) of the  $\alpha$ -phase, and halo patterns to (331) and (731) of the  $\gamma$ -phase were appreciable.

These observations lead us to conclude that the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples consisted of two different types of fine particles; one is the spheroid type shaped and well crystallized  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> and the other is the polyhedron type and not well crystallized  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>. In addition, for the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples with lower  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> contents, smaller polyhedrons of  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> were embedded in the larger  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> spheroids, while for the higher  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> contents the smaller  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> spheroids were surrounded by the polyhedrons of  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>.

### Photocatalytic reduction of CO<sub>2</sub> with water

All photocatalytic experiments have been performed over 5 hours to confirm that the production rates of H<sub>2</sub>, CO and O<sub>2</sub> became constant.

The dominant products of the photocatalytic reduction with water using the catalyst samples were H<sub>2</sub>, CO and O<sub>2</sub>. Their production rates satisfied the stoichiometry of  $([H_2] + [CO])/[O_2] = 1$ , where  $[H_2]$ ,  $[CO]$ , and  $[O_2]$  are the production rates of H<sub>2</sub>, CO, and O<sub>2</sub>, respectively. In Fig. 9 are plotted the production rates of H<sub>2</sub> and CO for all catalyst samples against the contents of the  $\gamma$ -phase. The CO production rates increased by increasing the  $\gamma$ -phase content up to 40% and then decreased. Over 60% the CO production rates became small without clear correlation with the  $\gamma$ -phase contents. The H<sub>2</sub> production rates were high for samples with lower  $\gamma$ -phase contents, while they were small for those samples with higher  $\gamma$ -phase contents over 60%. Both production rates seem differently depend on the  $\gamma$ -phase contents. However, as shown in Fig. 10 the ratios of the production rates of H<sub>2</sub> and CO are clearly correlated with the  $\gamma$ -

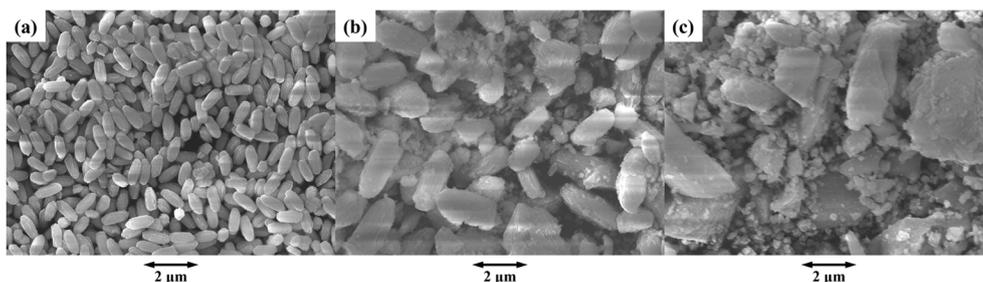


Fig. 7 SEM images of (a)  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>, (b)  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> with a  $\gamma$  phase content of 40% and (c)  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>.



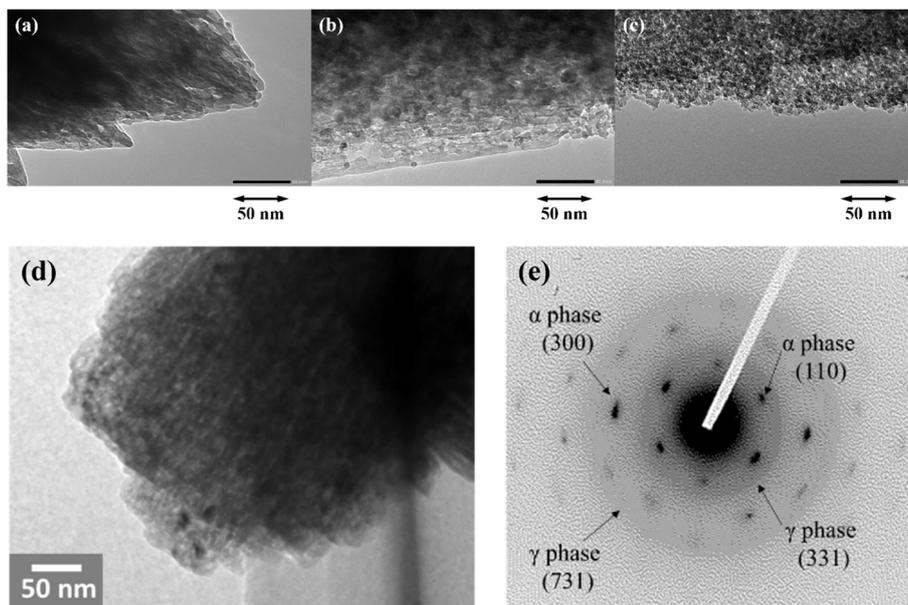


Fig. 8 TEM images of (a)  $\alpha$ - $\text{Ga}_2\text{O}_3$ , (b)  $\alpha/\gamma$ - $\text{Ga}_2\text{O}_3$  with a  $\gamma$  phase content of 40% and (c)  $\gamma$ - $\text{Ga}_2\text{O}_3$ , and (d) the enlarged image of a particle appeared in (b) and (e) its electron diffraction pattern.

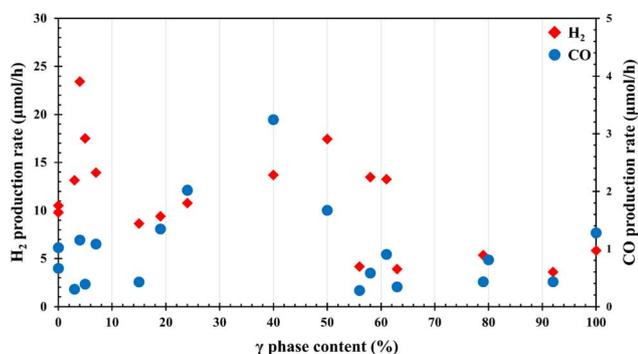


Fig. 9 Production rates of  $\text{H}_2$  and  $\text{CO}$  plotted against the  $\gamma$  phase contents of the  $\alpha/\gamma$ - $\text{Ga}_2\text{O}_3$  samples.

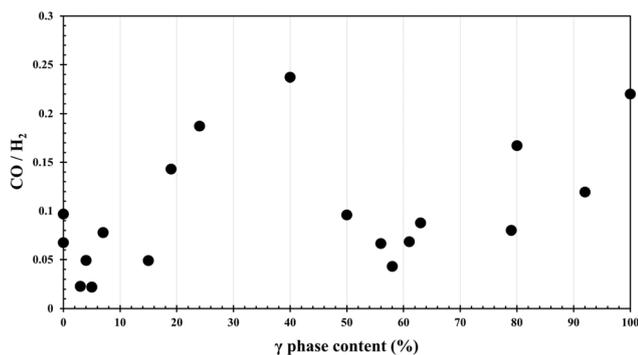


Fig. 10 Ratios of the production rates of  $\text{CO}$  and  $\text{H}_2$  plotted against the  $\gamma$  phase contents of the  $\alpha/\gamma$ - $\text{Ga}_2\text{O}_3$  samples.

phase contents. Furthermore, the figure suggests that the reaction mechanism changes in the samples with  $\gamma$ -phase

contents of below and above 60%. The reaction mechanism is discussed separately in the next section.

After the photocatalytic reduction, XRD and UV-vis of the samples showed no significant change except the new appearance of a small peak attributed to  $\text{GaOOH}$  in XRD.

## Discussion

As seen in Fig. 5, BET surface areas of the  $\alpha/\gamma$   $\text{Ga}_2\text{O}_3$  samples roughly linearly increased with the  $\gamma$ -phase contents and are well represented by the linear combination of those of the pure  $\alpha$ -phase and pure  $\gamma$ -phase with the coefficient of each phase. This indicates that the BET surface areas of both the phases in the  $\alpha/\gamma$   $\text{Ga}_2\text{O}_3$  samples were not influenced by the phase mixing. The observation of UV-vis also supports this. In addition, those of the  $\alpha/\gamma$   $\text{Ga}_2\text{O}_3$  samples were dominated by the BET surface area of the  $\gamma$ -phase. This is because the  $\gamma$ -phase was not well crystallized or included various defects as indicated by its broad X-ray spectrum in Fig. 1 and the halo patterns of TEM diffraction in Fig. 8(e). In addition, the activity of the  $\alpha/\gamma$   $\text{Ga}_2\text{O}_3$  samples with  $\gamma$ -phase contents more than 60% was weak similar to or even less than that of the pure  $\gamma$ -phase. The difference more clearly appeared in the ratio of the production rates of  $\text{H}_2$  and to  $\text{CO}$  (see Fig. 10), indicating that the mechanism of  $\text{CO}_2$  reduction was different between the samples containing the  $\gamma$ -phase less than 60% and higher ones.

In the following, discussed is the mechanism of higher activity of the samples containing the  $\gamma$ -phase less than 60%. As seen in Fig. 9,  $\text{H}_2$  is mainly formed on the  $\alpha$ -phase, while  $\text{CO}$  production increased by increasing the  $\gamma$ -phase content, reaching a maximum at about 40%  $\gamma$ -phase, and then decreasing despite the increase in the BET surface area. Considering redox type photocatalytic water splitting on the



Ga<sub>2</sub>O<sub>3</sub> catalyst indicated in previous studies, the present results strongly suggest that the H produced on the  $\alpha$ -phase by the water splitting is used to reduce the CO<sub>2</sub> adsorbed on the  $\gamma$ -phase, which has a large specific surface area.<sup>7-12</sup> In the previous studies, we have confirmed the surface adsorption of CO<sub>2</sub> as carbonate forms on Ga<sub>2</sub>O<sub>3</sub>.<sup>11,16,17</sup>

Based on this, we assume that some of the H produced on  $\alpha$ - and  $\gamma$ -phases in the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> sample reduces CO<sub>2</sub> adsorbed on either the  $\alpha$ - or  $\gamma$ -phase and estimate how CO<sub>2</sub> reduction rates change with the mixing ratio of  $\alpha/\gamma$ -phases. Considering the

BET surface change given in Fig. 5, we have employed an additional assumption that H production rates on the  $\alpha$ -phase and the  $\gamma$ -phase do not change with the mixing. Then CO production rates in the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples can be calculated as follows. The reaction rates of hydrogen and CO on the  $\alpha$  and  $\gamma$  phases are set to be  $\nu(\text{H}_2)_\alpha$  and  $\nu(\text{CO})_\alpha$ , and  $\nu(\text{H}_2)_\gamma$  and  $\nu(\text{CO})_\gamma$ , respectively, which are given as observed experimental values for the  $\alpha$  and  $\gamma$  single phase samples. Then the CO generation on the mixed phase samples can be divided into the following three contributions; (1) CO generation caused by hydrogen generated on the  $\alpha$  phase, (2) CO generation caused by hydrogen generated on the  $\gamma$  phase, and (3) CO generation on the  $\gamma$  phase caused by hydrogen generated on the  $\alpha$  phase with the efficiency of  $k$ .

Since the hydrogen production rate on each phase in a  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> sample should be proportional to the respective content of the  $\alpha$ - and  $\gamma$ -phases, the CO production rates for the above three contributions are given as  $(1-x)\nu(\text{CO})_\alpha$ ,  $x\nu(\text{CO})_\gamma$ , and  $k(1-x)x\nu(\text{H}_2)_\alpha$ , respectively. Here  $x$  is the content of the  $\gamma$ -phase. Then the total CO production rate in the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples is represented as

$$\nu(\text{CO})_{\text{total}} = (1-x)\nu(\text{CO})_\alpha + x\nu(\text{CO})_\gamma + k(x-x^2)(\nu(\text{H}_2)_\alpha) \quad (1)$$

In Fig. 11, eqn (4) with the adjustment of  $k$  to fit the experimental results is superposed on the experimentally obtained CO<sub>2</sub> production rates. Although the data are scattered, the model calculation fits well. And the third term of eqn (1) dominates in the total reaction rates. This means that the CO<sub>2</sub> reduction on the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples is dominated by the reaction that H produced on the  $\alpha$ -phase is used to reduce CO<sub>2</sub> adsorbed on the  $\gamma$ -phase.

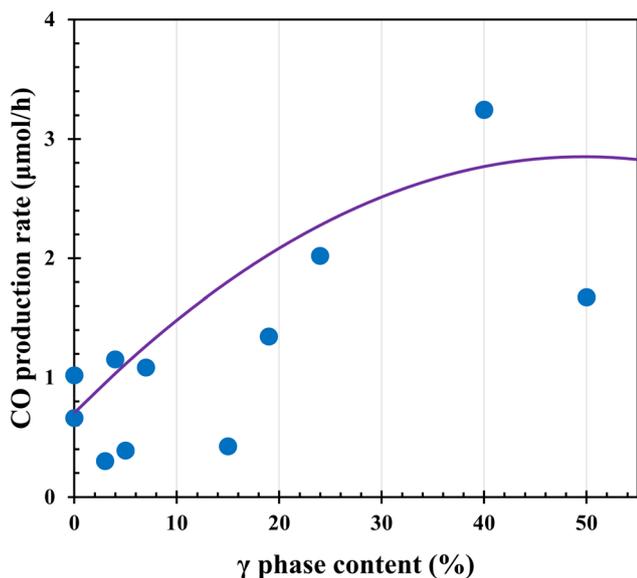


Fig. 11 Comparison of CO production rates estimated by eqn (4) with the observed ones for the  $\alpha/\gamma$  Ga<sub>2</sub>O<sub>3</sub> samples with a  $\gamma$  phase content up to 50%.

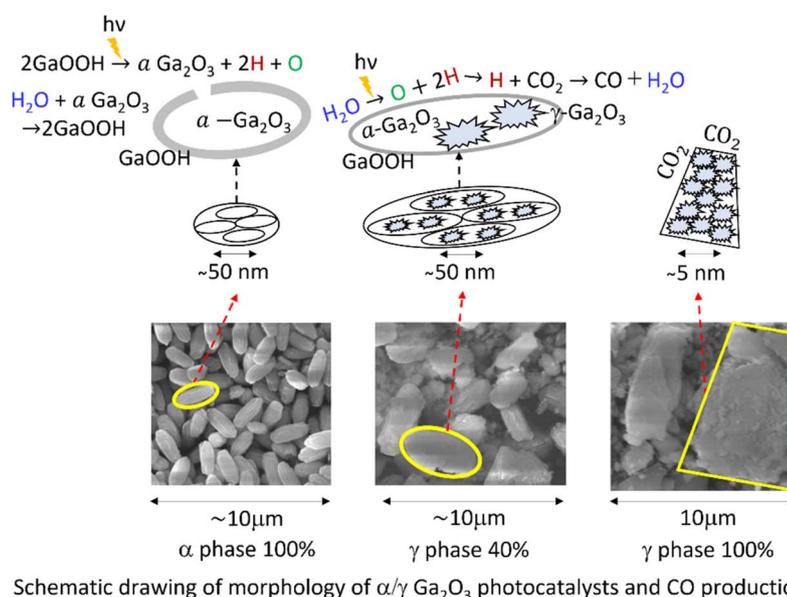


Fig. 12 Schematic drawing of the CO production mechanism on the  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> samples and morphologies of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>,  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> with the  $\gamma$ -concentration of 40% and  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> (see text).



In the previous work, Aoki *et al.* indicated that photocatalytic water splitting on  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> proceeds through the following redox reactions of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> and GaOOH.<sup>9,12</sup>

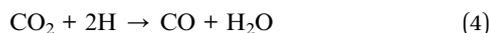
In water, the surface of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> is oxyhydrated as,



and photo-irradiation reduces GaOOH producing H and O as,



Thus produced H reduces CO<sub>2</sub> as



In the present work, the formation of GaOOH was also observed in the XRD of the samples after use.

Considering all the above, the mechanism of the CO production on the mixed phase sample is schematically drawn as given in Fig. 12. From the morphology determined by XRD, SEM and TEM, the mixed phase samples consist of spheroid type  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles with smaller polyhedral type  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> which was not well crystallized to show a large surface area and embedded in the  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles. Hydrogen is dominantly produced on the  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles thorough the redox of Ga<sub>2</sub>O<sub>3</sub> and GaOOH and migrates to the  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> particles embedded in the larger  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles to reduce CO<sub>2</sub> adsorbed on it.

In samples containing the  $\gamma$ -phase more than 60%, the particles of  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> dominate to cover the minor  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles to inhibit oxyhydration of  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub>. Consequently, hydrogen production is suppressed resulting in less CO production. Although the oxyhydration of  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> would be possible, the product is very likely Ga(OH)<sub>3</sub> which is the precursor of  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> as seen in Fig. 1. The reduction of Ga(OH)<sub>3</sub> by photons would be possible



However, it requires major re-arrangement of Ga and O atoms, and the reaction would be harder to proceed. Accordingly, hydrogen production on the  $\gamma$ -phase is much less than that on the  $\alpha$ -phase.

## Conclusions

We have succeeded in synthesizing  $\alpha/\gamma$  mixed-phase gallium oxides ( $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub>) with controlled  $\alpha/\gamma$  mixing ratios by impregnation and calcination. The  $\alpha/\gamma$  phase mixing ratios were determined quantitatively by XAFS structural analysis with the Ga K-edge. The prepared  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> was used as the catalyst for the photoreduction of CO<sub>2</sub> with water. Although the specific surface areas of  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> nearly linearly increased from 38 m<sup>2</sup> g<sup>-1</sup> of the pure  $\alpha$ -phase to 130 m<sup>2</sup> g<sup>-1</sup> for the pure  $\gamma$ -phase, they did not correlate well with the catalytic activity or the production rates of H<sub>2</sub> and CO. Instead, the production rates of H<sub>2</sub> and CO appreciably changed with the mixing ratio. The H<sub>2</sub> formation dominated on the  $\alpha$ -phase, while the CO production

increased with increasing the  $\gamma$ -phase content and attained the maximum for a  $\gamma$ -content of 40%. Above 60% both the H<sub>2</sub> and CO production rates decreased to the similar rates of the pure  $\gamma$ -phase much less than that of the pure  $\alpha$ -phase. The ratio of the production rates of H<sub>2</sub> and CO also increased with increasing the  $\gamma$ -content to the maximum at a  $\gamma$ -content of 40%. Above 40%, it decreased taking a minimum and then increased again suggesting a different mechanism for  $\alpha$ -dominated and  $\gamma$ -dominated  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub>.

According to a reaction mechanism in the previous work, CO production in the photocatalytic CO<sub>2</sub> reduction with water on  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> catalysts proceeds through the reaction of adsorbed CO<sub>2</sub> with H produced by the water splitting. In analogy with this mechanism, we have assumed that some of the H produced on the  $\alpha$ -phase reduces CO<sub>2</sub> adsorbed on the  $\gamma$ -phase and made a kinetic equation to give the CO production rate taking into account the H production rate on the  $\alpha$  phase and CO production rates with the reaction of H produced on the  $\alpha$ -phase and CO<sub>2</sub> adsorbed on the  $\gamma$  phase, and the contents of both the phases. The equation fits well to the observed relation of the CO production rates with the  $\alpha/\gamma$  mixing ratio up to a  $\gamma$  content of 50%. This confirms the reaction mechanism that H produced on the  $\alpha$ -phase reduces CO<sub>2</sub> adsorbed on the  $\gamma$ -phase.

TEM observations of  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> revealed that the spheroid type  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles were coexisting with smaller polyhedral type  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> which was not well crystallized to show a large surface area. In  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> containing the  $\gamma$ -phase less than 40%,  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> particles were embedded in the  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles, while in  $\alpha/\gamma$ -Ga<sub>2</sub>O<sub>3</sub> containing the  $\gamma$ -phase more than 60%  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> particles covered  $\alpha$ -Ga<sub>2</sub>O<sub>3</sub> particles. These observations well correspond to the above reaction mechanism below 50% and similar activities with the  $\gamma$ -phase for above 60%.

## Data availability

Raw data were generated at Osaka Metropolitan University. Derived data supporting the findings of this study are available from Tomoko Yoshida on request.

## Conflicts of interest

The authors declare no conflict of interest.

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